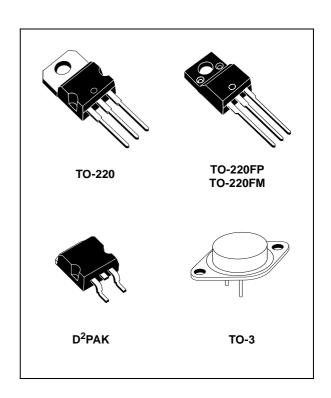


POSITIVE VOLTAGE REGULATORS

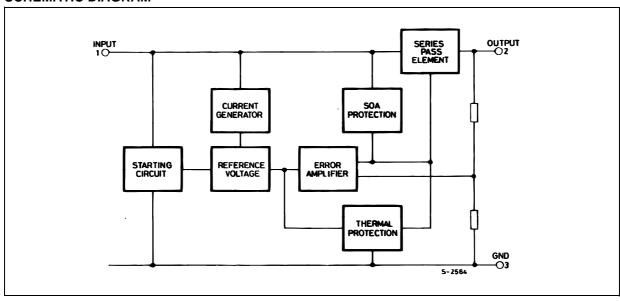
- OUTPUT CURRENT TO 1.5A
- OUTPUT VOLTAGES OF 5; 5.2; 6; 8; 8.5; 9; 12; 15; 18; 24V
- THERMAL OVERLOAD PROTECTION
- SHORT CIRCUIT PROTECTION
- OUTPUT TRANSITION SOA PROTECTION

DESCRIPTION

The L7800 series of three-terminal positive regulators is available in TO-220, TO-220FP, TO-220FM, TO-3 and D²PAK packages and several fixed output voltages, making it useful in a wide range of applications. These regulators can provide local on-card regulation, eliminating the distribution problems associated with single point regulation. Each type employs internal current limiting, thermal shut-down and safe area protection, making it essentially indestructible. If adequate heat sinking is provided, they can deliver over 1A output current. Although designed primarily as fixed voltage regulators, these devices can be used with external components to obtain adjustable voltage and currents.



SCHEMATIC DIAGRAM



April 2004 1/33

ABSOLUTE MAXIMUM RATINGS

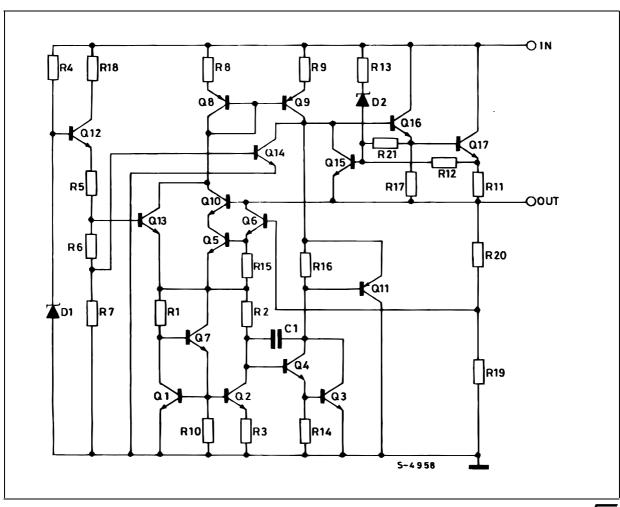
Symbol	Para	meter	Value	Unit
\/	DC Input Voltage	for V _O = 5 to 18V	35	.,
VI		for V _O = 20, 24V	40	V
Io	Output Current	Current Internally Limited		
P _{tot}	Power Dissipation		Internally Limited	
T _{stg}	Storage Temperature Range		-65 to 150	°C
т	Operating Junction Temperature	for L7800	-55 to 150	°C
T_{op}	Range	for L7800C	0 to 150	

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.

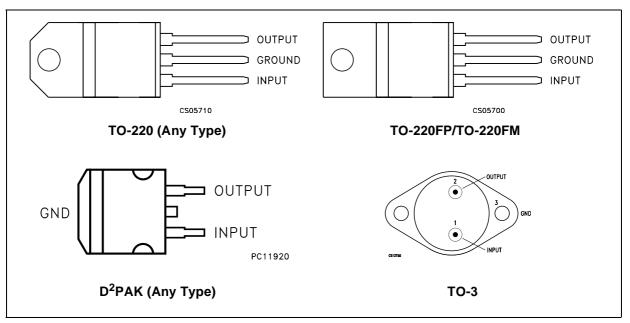
THERMAL DATA

Symbol	Parameter	D ² PAK	TO-220	TO-220FP	TO-220FM	TO-3	Unit
R _{thj-case}	Thermal Resistance Junction-case Max	3	5	5	5	4	°C/W
R _{thj-amb}	Thermal Resistance Junction-ambient Max	62.5	50	60	60	35	°C/W

SCHEMATIC DIAGRAM



CONNECTION DIAGRAM (top view)

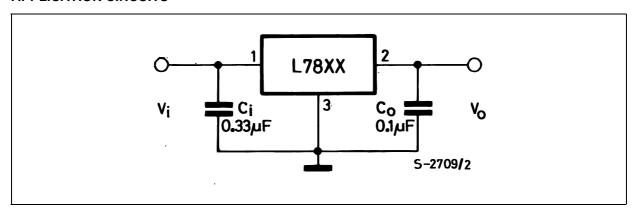


ORDERING CODES

TYPE	TO-220 (A Type)	TO-220 (C Type)	TO-220 (E Type)	D ² PAK (A Type) (*)	D ² PAK (C Type) (T & R)	TO-220FP	TO-220FM	TO-3
L7805								L7805T
L7805C	L7805CV	L7805C-V	L7805CV1	L7805CD2T	L7805C-D2TR	L7805CP	L7805CF	L7805CT
L7852C	L7852CV			L7852CD2T		L7852CP	L7852CF	L7852CT
L7806								L7806T
L7806C	L7806CV	L7806C-V		L7806CD2T		L7806CP	L7806CF	L7806CT
L7808								L7808T
L7808C	L7808CV	L7808C-V		L7808CD2T		L7808CP	L7808CF	L7808CT
L7885C	L7885CV			L7885CD2T		L7885CP	L7885CF	L7885CT
L7809C	L7809CV	L7809C-V		L7809CD2T		L7809CP	L7809CF	L7809CT
L7812								L7812T
L7812C	L7812CV	L7812C-V		L7812CD2T		L7812CP	L7812CF	L7812CT
L7815								L7815T
L7815C	L7815CV	L7815C-V		L7815CD2T		L7815CP	L7815CF	L7815CT
L7818								L7818T
L7818C	L7818CV			L7818CD2T		L7818CP	L7818CF	L7818CT
L7820								L7820T
L7820C	L7820CV			L7820CD2T		L7820CP	L7820CF	L7820CT
L7824								L7824T
L7824C	L7824CV		_	L7824CD2T		L7824CP	L7824CF	L7824CT

^(*) Available in Tape & Reel with the suffix "-TR".

APPLICATION CIRCUITS



TEST CIRCUITS

Figure 1 : DC Parameter

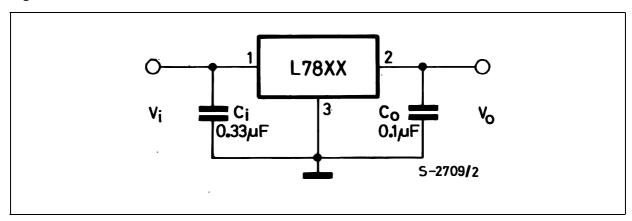


Figure 2: Load Regulation

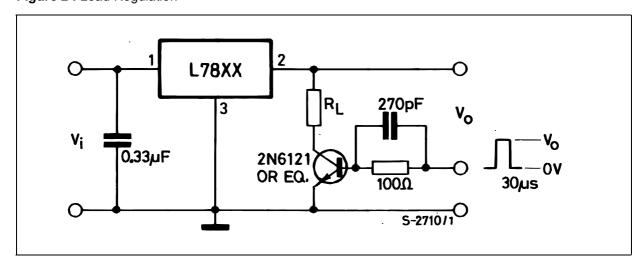
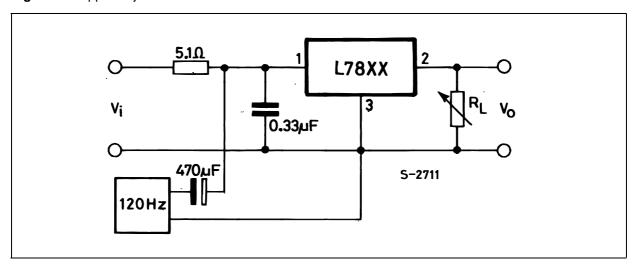


Figure 3: Ripple Rejection



ELECTRICAL CHARACTERISTICS OF L7805 (refer to the test circuits, T_J = -55 to 150°C, V_I = 10V, I_O = 500 mA, C_I = 0.33 μ F, C_O = 0.1 μ F unless otherwise specified).

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Vo	Output Voltage	$T_J = 25$ °C	4.8	5	5.2	V
Vo	Output Voltage	I_O = 5 mA to 1 A $P_O \le 15W$ V_I = 8 to 20 V	4.65	5	5.35	V
ΔV _O (*)	Line Regulation	$V_{I} = 7 \text{ to } 25 \text{ V}$ $T_{J} = 25^{\circ}\text{C}$		3	50	mV
		V _I = 8 to 12 V T _J = 25°C		1	25	
ΔV _O (*)	Load Regulation	$I_O = 5 \text{ mA to } 1.5 \text{ A}$ $T_J = 25^{\circ}\text{C}$			100	mV
		$I_{O} = 250 \text{ to } 750 \text{ mA}$ $T_{J} = 25^{\circ}\text{C}$			25	1
I _d	Quiescent Current	T _J = 25°C			6	mA
ΔI_d	Quiescent Current Change	I _O = 5 mA to 1 A			0.5	mA
		V _I = 8 to 25 V			0.8	
$\Delta V_{O}/\Delta T$	Output Voltage Drift	$I_O = 5 \text{ mA}$		0.6		mV/°C
eN	Output Noise Voltage	B =10Hz to 100KHz $T_J = 25$ °C			40	μV/V _O
SVR	Supply Voltage Rejection	V _I = 8 to 18 V f = 120Hz	68			dB
V _d	Dropout Voltage	I _O = 1 A T _J = 25°C		2	2.5	V
R _O	Output Resistance	f = 1 KHz		17		mΩ
I _{sc}	Short Circuit Current	V _I = 35 V T _J = 25°C		0.75	1.2	Α
I _{scp}	Short Circuit Peak Current	T _J = 25°C	1.3	2.2	3.3	Α

^(*) Load and line regulation are specified at constant junction temperature. Changes in V_0 due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

ELECTRICAL CHARACTERISTICS OF L7806 (refer to the test circuits, T_J = -55 to 150°C, V_I = 11V, I_O = 500 mA, C_I = 0.33 μ F, C_O = 0.1 μ F unless otherwise specified).

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Vo	Output Voltage	T _J = 25°C	5.75	6	6.25	V
Vo	Output Voltage	$I_O = 5 \text{ mA to 1 A}$ $P_O \le 15W$ $V_I = 9 \text{ to 21 V}$	5.65	6	6.35	V
ΔV _O (*)	Line Regulation	$V_{I} = 8 \text{ to } 25 \text{ V}$ $T_{J} = 25^{\circ}\text{C}$			60	mV
		$V_{I} = 9 \text{ to } 13 \text{ V}$ $T_{J} = 25^{\circ}\text{C}$			30	
ΔV _O (*)	Load Regulation	$I_O = 5 \text{ mA to } 1.5 \text{ A}$ $T_J = 25^{\circ}\text{C}$			100	mV
		$I_{O} = 250 \text{ to } 750 \text{ mA}$ $T_{J} = 25^{\circ}\text{C}$			30	
I _d	Quiescent Current	T _J = 25°C			6	mA
Δl _d	Quiescent Current Change	I _O = 5 mA to 1 A			0.5	mA
		V _I = 9 to 25 V			0.8	
$\Delta V_{O}/\Delta T$	Output Voltage Drift	$I_O = 5 \text{ mA}$		0.7		mV/°C
eN	Output Noise Voltage	B = 10Hz to 100KHz $T_J = 25$ °C			40	μV/V _O
SVR	Supply Voltage Rejection	V _I = 9 to 19 V f = 120Hz	65			dB
V _d	Dropout Voltage	I _O = 1 A T _J = 25°C		2	2.5	V
R _O	Output Resistance	f = 1 KHz		19		mΩ
I _{sc}	Short Circuit Current	V _I = 35 V T _J = 25°C		0.75	1.2	Α
I _{scp}	Short Circuit Peak Current	T _J = 25°C	1.3	2.2	3.3	Α

^(*) Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

ELECTRICAL CHARACTERISTICS OF L7808 (refer to the test circuits, T_J = -55 to 150°C, V_I = 14V, I_O = 500 mA, C_I = 0.33 μ F, C_O = 0.1 μ F unless otherwise specified).

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Vo	Output Voltage	T _J = 25°C	7.7	8	8.3	V
Vo	Output Voltage	$I_O = 5 \text{ mA to 1 A}$ $P_O \le 15W$ $V_I = 11.5 \text{ to 23 V}$	7.6	8	8.4	V
ΔV _O (*)	Line Regulation	V _I = 10.5 to 25 V T _J = 25°C			80	mV
		V _I = 11 to 17 V T _J = 25°C			40	
$\Delta V_{O}(*)$	Load Regulation	$I_O = 5 \text{ mA to } 1.5 \text{ A}$ $T_J = 25^{\circ}\text{C}$			100	mV
		$I_{O} = 250 \text{ to } 750 \text{ mA}$ $T_{J} = 25^{\circ}\text{C}$			40	
I _d	Quiescent Current	T _J = 25°C			6	mA
ΔI_{d}	Quiescent Current Change	I _O = 5 mA to 1 A			0.5	mA
		V _I = 11.5 to 25 V			0.8	
$\Delta V_{O}/\Delta T$	Output Voltage Drift	I _O = 5 mA		1		mV/°C
eN	Output Noise Voltage	B =10Hz to 100KHz $T_J = 25$ °C			40	μV/V _O
SVR	Supply Voltage Rejection	V _I = 11.5 to 21.5 V f = 120Hz	62			dB
V _d	Dropout Voltage	$I_O = 1 \text{ A}$ $T_J = 25^{\circ}\text{C}$		2	2.5	V
R _O	Output Resistance	f = 1 KHz		16		mΩ
I _{sc}	Short Circuit Current	V _I = 35 V T _J = 25°C		0.75	1.2	Α
I _{scp}	Short Circuit Peak Current	$T_J = 25^{\circ}C$	1.3	2.2	3.3	Α

^(*) Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

ELECTRICAL CHARACTERISTICS OF L7812 (refer to the test circuits, T_J = -55 to 150°C, V_I = 19V, I_O = 500 mA, C_I = 0.33 μ F, C_O = 0.1 μ F unless otherwise specified).

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Vo	Output Voltage	T _J = 25°C	11.5	12	12.5	V
Vo	Output Voltage	$I_O = 5 \text{ mA to 1 A}$ $P_O \le 15W$ $V_I = 15.5 \text{ to 27 V}$	11.4	12	12.6	V
ΔV _O (*)	Line Regulation	$V_I = 14.5 \text{ to } 30 \text{ V}$ $T_J = 25^{\circ}\text{C}$			120	mV
		$V_{I} = 16 \text{ to } 22 \text{ V}$ $T_{J} = 25^{\circ}\text{C}$			60	
ΔV _O (*)	Load Regulation	$I_O = 5 \text{ mA to } 1.5 \text{ A}$ $T_J = 25^{\circ}\text{C}$			100	mV
		$I_{O} = 250 \text{ to } 750 \text{ mA}$ $T_{J} = 25^{\circ}\text{C}$			60	
I _d	Quiescent Current	$T_J = 25$ °C			6	mA
ΔI_{d}	Quiescent Current Change	I _O = 5 mA to 1 A			0.5	mA
		V _I = 15 to 30 V			0.8	
$\Delta V_{O}/\Delta T$	Output Voltage Drift	I _O = 5 mA		1.5		mV/°C
eN	Output Noise Voltage	B =10Hz to 100KHz $T_J = 25$ °C			40	μV/V _O
SVR	Supply Voltage Rejection	V _I = 15 to 25 V f = 120Hz	61			dB
V _d	Dropout Voltage	I _O = 1 A T _J = 25°C		2	2.5	V
R _O	Output Resistance	f = 1 KHz		18		mΩ
I _{sc}	Short Circuit Current	V _I = 35 V T _J = 25°C		0.75	1.2	Α
I _{scp}	Short Circuit Peak Current	T _J = 25°C	1.3	2.2	3.3	Α

^(*) Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

ELECTRICAL CHARACTERISTICS OF L7815 (refer to the test circuits, T_J = -55 to 150°C, V_I = 23V, I_O = 500 mA, C_I = 0.33 μ F, C_O = 0.1 μ F unless otherwise specified).

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Vo	Output Voltage	T _J = 25°C	14.4	15	15.6	V
Vo	Output Voltage	$I_O = 5 \text{ mA to } 1 \text{ A}$ $P_O \le 15W$ $V_I = 18.5 \text{ to } 30 \text{ V}$	14.25	15	15.75	V
ΔV _O (*)	Line Regulation	$V_{I} = 17.5 \text{ to } 30 \text{ V}$ $T_{J} = 25^{\circ}\text{C}$			150	mV
		V _I = 20 to 26 V			75	
ΔV _O (*)	Load Regulation	$I_O = 5$ mA to 1.5 A $T_J = 25$ °C			150	mV
		$I_{O} = 250 \text{ to } 750 \text{ mA}$ $T_{J} = 25^{\circ}\text{C}$			75	
I _d	Quiescent Current	T _J = 25°C			6	mA
ΔI_{d}	Quiescent Current Change	I _O = 5 mA to 1 A			0.5	mA
		V _I = 18.5 to 30 V			0.8	
$\Delta V_{O}/\Delta T$	Output Voltage Drift	I _O = 5 mA		1.8		mV/°C
eN	Output Noise Voltage	B =10Hz to 100KHz $T_J = 25$ °C			40	μV/V _O
SVR	Supply Voltage Rejection	V _I = 18.5 to 28.5 V f = 120Hz	60			dB
V _d	Dropout Voltage	I _O = 1 A T _J = 25°C		2	2.5	V
R _O	Output Resistance	f = 1 KHz		19		mΩ
I _{sc}	Short Circuit Current	$V_{I} = 35 \text{ V}$ $T_{J} = 25^{\circ}\text{C}$		0.75	1.2	Α
I _{scp}	Short Circuit Peak Current	T _J = 25°C	1.3	2.2	3.3	А

^(*) Load and line regulation are specified at constant junction temperature. Changes in V_0 due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

ELECTRICAL CHARACTERISTICS OF L7818 (refer to the test circuits, T_J = -55 to 150°C, V_I = 26V, I_O = 500 mA, C_I = 0.33 μ F, C_O = 0.1 μ F unless otherwise specified).

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Vo	Output Voltage	T _J = 25°C	17.3	18	18.7	V
Vo	Output Voltage	$I_O = 5 \text{ mA to 1 A}$ $P_O \le 15W$ $V_I = 22 \text{ to 33 V}$	17.1	18	18.9	V
ΔV _O (*)	Line Regulation	$V_{I} = 21 \text{ to } 33 \text{ V}$ $T_{J} = 25^{\circ}\text{C}$			180	mV
		V _I = 24 to 30 V			90	
ΔV _O (*)	Load Regulation	$I_{O} = 5 \text{ mA to } 1.5 \text{ A}$ $T_{J} = 25^{\circ}\text{C}$			180	mV
		$I_{O} = 250 \text{ to } 750 \text{ mA}$ $T_{J} = 25^{\circ}\text{C}$			90	
I _d	Quiescent Current	T _J = 25°C			6	mA
Δl _d	Quiescent Current Change	I _O = 5 mA to 1 A			0.5	mA
		V _I = 22 to 33 V			0.8	
$\Delta V_{O}/\Delta T$	Output Voltage Drift	I _O = 5 mA		2.3		mV/°C
eN	Output Noise Voltage	B =10Hz to 100KHz $T_J = 25$ °C			40	μV/V _O
SVR	Supply Voltage Rejection	V _I = 22 to 32 V f = 120Hz	59			dB
V _d	Dropout Voltage	I _O = 1 A T _J = 25°C		2	2.5	V
R _O	Output Resistance	f = 1 KHz		22		mΩ
I _{sc}	Short Circuit Current	V _I = 35 V T _J = 25°C		0.75	1.2	Α
I _{scp}	Short Circuit Peak Current	T _J = 25°C	1.3	2.2	3.3	Α

^(*) Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

ELECTRICAL CHARACTERISTICS OF L7820 (refer to the test circuits, T_J = -55 to 150°C, V_I = 28V, I_O = 500 mA, C_I = 0.33 μ F, C_O = 0.1 μ F unless otherwise specified).

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Vo	Output Voltage	T _J = 25°C	19.2	20	20.8	V
Vo	Output Voltage	$I_O = 5 \text{ mA to 1 A}$ $P_O \le 15W$	19	20	21	V
		$V_1 = 24 \text{ to } 35 \text{ V}$				
$\Delta V_{O}(*)$	Line Regulation	$V_I = 22.5 \text{ to } 35 \text{ V}$ $T_J = 25^{\circ}\text{C}$			200	mV
		$V_{I} = 26 \text{ to } 32 \text{ V}$ $T_{J} = 25 ^{\circ}\text{C}$			100	
$\Delta V_{O}(*)$	Load Regulation	$I_O = 5 \text{ mA to } 1.5 \text{ A}$ $T_J = 25^{\circ}\text{C}$			200	mV
		$I_{O} = 250 \text{ to } 750 \text{ mA}$ $T_{J} = 25^{\circ}\text{C}$			100	
I _d	Quiescent Current	$T_J = 25$ °C			6	mA
ΔI_d	Quiescent Current Change	$I_O = 5 \text{ mA to } 1 \text{ A}$			0.5	mA
		V _I = 24 to 35 V			0.8	
$\Delta V_O/\Delta T$	Output Voltage Drift	$I_O = 5 \text{ mA}$		2.5		mV/°C
eN	Output Noise Voltage	B =10Hz to 100KHz $T_J = 25$ °C			40	μV/V _O
SVR	Supply Voltage Rejection	$V_1 = 24 \text{ to } 35 \text{ V}$ $f = 120 \text{Hz}$	58			dB
V _d	Dropout Voltage	I _O = 1 A T _J = 25°C		2	2.5	V
R _O	Output Resistance	f = 1 KHz		24		mΩ
I _{sc}	Short Circuit Current	V _I = 35 V T _J = 25°C		0.75	1.2	Α
I _{scp}	Short Circuit Peak Current	T _J = 25°C	1.3	2.2	3.3	Α

^(*) Load and line regulation are specified at constant junction temperature. Changes in V_0 due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

ELECTRICAL CHARACTERISTICS OF L7824 (refer to the test circuits, T_J = -55 to 150°C, V_I = 33V, I_O = 500 mA, C_I = 0.33 μ F, C_O = 0.1 μ F unless otherwise specified).

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Vo	Output Voltage	T _J = 25°C	23	24	25	V
Vo	Output Voltage	$I_O = 5$ mA to 1 A $P_O \le 15$ W $V_I = 28$ to 38 V	22.8	24	25.2	V
ΔV _O (*)	Line Regulation	$V_{I} = 27 \text{ to } 38 \text{ V}$ $T_{J} = 25^{\circ}\text{C}$			240	mV
		$V_{I} = 30 \text{ to } 36 \text{ V}$ $T_{J} = 25^{\circ}\text{C}$			120	
ΔV _O (*)	Load Regulation	$I_{O} = 5 \text{ mA to } 1.5 \text{ A}$ $T_{J} = 25^{\circ}\text{C}$			240	mV
		$I_{O} = 250 \text{ to } 750 \text{ mA}$ $T_{J} = 25^{\circ}\text{C}$			120	
I _d	Quiescent Current	T _J = 25°C			6	mA
ΔI_{d}	Quiescent Current Change	I _O = 5 mA to 1 A			0.5	mA
		V _I = 28 to 38 V			0.8	
$\Delta V_O/\Delta T$	Output Voltage Drift	I _O = 5 mA		3		mV/°C
eN	Output Noise Voltage	B =10Hz to 100KHz $T_J = 25$ °C			40	μV/V _O
SVR	Supply Voltage Rejection	V _I = 28 to 38 V f = 120Hz	56			dB
V _d	Dropout Voltage	I _O = 1 A T _J = 25°C		2	2.5	V
R _O	Output Resistance	f = 1 KHz		28		mΩ
I _{sc}	Short Circuit Current	V _I = 35 V T _J = 25°C		0.75	1.2	Α
I _{scp}	Short Circuit Peak Current	T _J = 25°C	1.3	2.2	3.3	Α

^(*) Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

ELECTRICAL CHARACTERISTICS OF L7805C (refer to the test circuits, T_J = 0 to 125°C, V_I = 10V, I_O = 500 mA, C_I = 0.33 μ F, C_O = 0.1 μ F unless otherwise specified).

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Vo	Output Voltage	T _J = 25°C	4.8	5	5.2	V
Vo	Output Voltage	$I_O = 5 \text{ mA to 1 A}$ $P_O \le 15W$ $V_I = 7 \text{ to 20 V}$	4.75	5	5.25	V
$\Delta V_{O}(*)$	Line Regulation	$V_{I} = 7 \text{ to } 25 \text{ V}$ $T_{J} = 25^{\circ}\text{C}$		3	100	mV
		$V_{I} = 8 \text{ to } 12 \text{ V}$ $T_{J} = 25^{\circ}\text{C}$		1	50	
ΔV _O (*)	Load Regulation	$I_O = 5 \text{ mA to } 1.5 \text{ A}$ $T_J = 25^{\circ}\text{C}$			100	mV
		$I_{O} = 250 \text{ to } 750 \text{ mA}$ $T_{J} = 25^{\circ}\text{C}$			50	
I _d	Quiescent Current	$T_J = 25$ °C			8	mA
ΔI_d	Quiescent Current Change	I _O = 5 mA to 1 A			0.5	mA
		V _I = 7 to 25 V			0.8	
$\Delta V_{O}/\Delta T$	Output Voltage Drift	I _O = 5 mA		-1.1		mV/°C
eN	Output Noise Voltage	B =10Hz to 100KHz $T_J = 25$ °C		40		μV/V _O
SVR	Supply Voltage Rejection	V _I = 8 to 18 V f = 120Hz	62			dB
V _d	Dropout Voltage	$I_O = 1 \text{ A}$ $T_J = 25^{\circ}\text{C}$		2		V
R _O	Output Resistance	f = 1 KHz		17		mΩ
I _{sc}	Short Circuit Current	V _I = 35 V T _J = 25°C		0.75		А
I _{scp}	Short Circuit Peak Current	$T_J = 25$ °C		2.2		Α

^(*) Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

ELECTRICAL CHARACTERISTICS OF L7852C (refer to the test circuits, T_J = 0 to 125°C, V_I = 10V, I_O = 500 mA, C_I = 0.33 μ F, C_O = 0.1 μ F unless otherwise specified).

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Vo	Output Voltage	T _J = 25°C	5.0	5.2	5.4	V
Vo	Output Voltage	$I_O = 5 \text{ mA to 1 A} \qquad P_O \le 15W$ $V_I = 8 \text{ to 20 V}$	4.95	5.2	5.45	V
ΔV _O (*)	Line Regulation	$V_{I} = 7 \text{ to } 25 \text{ V}$ $T_{J} = 25^{\circ}\text{C}$		3	105	mV
		$V_I = 8 \text{ to } 12 \text{ V}$ $T_J = 25^{\circ}\text{C}$		1	52	
ΔV _O (*)	Load Regulation	$I_O = 5 \text{ mA to } 1.5 \text{ A}$ $T_J = 25^{\circ}\text{C}$			105	mV
		$I_{O} = 250 \text{ to } 750 \text{ mA}$ $T_{J} = 25^{\circ}\text{C}$			52	
I _d	Quiescent Current	$T_J = 25$ °C			8	mA
ΔI_{d}	Quiescent Current Change	I _O = 5 mA to 1 A			0.5	mA
		V _I = 7 to 25 V			1.3	
$\Delta V_O/\Delta T$	Output Voltage Drift	$I_O = 5 \text{ mA}$		-1		mV/°C
eN	Output Noise Voltage	B =10Hz to 100KHz $T_J = 25$ °C		42		μV/V _O
SVR	Supply Voltage Rejection	V _I = 8 to 18 V f = 120Hz	61			dB
V _d	Dropout Voltage	I _O = 1 A T _J = 25°C		2		V
R _O	Output Resistance	f = 1 KHz		17		mΩ
I _{sc}	Short Circuit Current	V _I = 35 V T _J = 25°C		0.75		Α
I _{scp}	Short Circuit Peak Current	$T_J = 25^{\circ}C$		2.2		Α

^(*) Load and line regulation are specified at constant junction temperature. Changes in V_0 due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

ELECTRICAL CHARACTERISTICS OF L7806C (refer to the test circuits, T_J = 0 to 125°C, V_I = 11V, I_O = 500 mA, C_I = 0.33 μ F, C_O = 0.1 μ F unless otherwise specified).

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Vo	Output Voltage	T _J = 25°C	5.75	6	6.25	V
Vo	Output Voltage	$I_O = 5$ mA to 1 A $P_O \le 15$ W $V_I = 8$ to 21 V	5.7	6	6.3	V
$\Delta V_{O}(*)$	Line Regulation	$V_{I} = 8 \text{ to } 25 \text{ V}$ $T_{J} = 25^{\circ}\text{C}$			120	mV
		V _I = 9 to 13 V T _J = 25°C			60	
ΔV _O (*)	Load Regulation	$I_O = 5 \text{ mA to } 1.5 \text{ A}$ $T_J = 25^{\circ}\text{C}$			120	mV
		$I_{O} = 250 \text{ to } 750 \text{ mA}$ $T_{J} = 25^{\circ}\text{C}$			60	
I _d	Quiescent Current	T _J = 25°C			8	mA
ΔI_d	Quiescent Current Change	I _O = 5 mA to 1 A			0.5	mA
		V _I = 8 to 25 V			1.3	
$\Delta V_{O}/\Delta T$	Output Voltage Drift	I _O = 5 mA		-0.8		mV/°C
eN	Output Noise Voltage	B =10Hz to 100KHz $T_J = 25$ °C		45		μV/V _O
SVR	Supply Voltage Rejection	V _I = 9 to 19 V f = 120Hz	59			dB
V _d	Dropout Voltage	I _O = 1 A T _J = 25°C		2		V
R _O	Output Resistance	f = 1 KHz		19		mΩ
I _{sc}	Short Circuit Current	V _I = 35 V T _J = 25°C		0.55		Α
I _{scp}	Short Circuit Peak Current	T _J = 25°C		2.2		Α

^(*) Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

ELECTRICAL CHARACTERISTICS OF L7808C (refer to the test circuits, T_J = 0 to 125°C, V_I = 14V, I_O = 500 mA, C_I = 0.33 μ F, C_O = 0.1 μ F unless otherwise specified).

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Vo	Output Voltage	$T_J = 25^{\circ}C$	7.7	8	8.3	V
Vo	Output Voltage	$I_O = 5 \text{ mA to } 1 \text{ A}$ $P_O \le 15W$ $V_I = 10.5 \text{ to } 25 \text{ V}$	7.6	8	8.4	V
ΔV _O (*)	Line Regulation	$V_{I} = 10.5 \text{ to } 25 \text{ V}$ $T_{J} = 25^{\circ}\text{C}$			160	mV
		$V_{I} = 11 \text{ to } 17 \text{ V}$ $T_{J} = 25^{\circ}\text{C}$			80	
ΔV _O (*)	Load Regulation	$I_O = 5 \text{ mA to } 1.5 \text{ A}$ $T_J = 25^{\circ}\text{C}$			160	mV
		$I_{O} = 250 \text{ to } 750 \text{ mA}$ $T_{J} = 25^{\circ}\text{C}$			80	
I _d	Quiescent Current	$T_J = 25$ °C			8	mA
ΔI_{d}	Quiescent Current Change	$I_O = 5 \text{ mA to } 1 \text{ A}$			0.5	mA
		V _I = 10.5 to 25 V			1	
$\Delta V_{O}/\Delta T$	Output Voltage Drift	I _O = 5 mA		-0.8		mV/°C
eN	Output Noise Voltage	B =10Hz to 100KHz $T_J = 25$ °C		52		μV/V _O
SVR	Supply Voltage Rejection	V _I = 11.5 to 21.5 V f = 120Hz	56			dB
V _d	Dropout Voltage	I _O = 1 A T _J = 25°C		2		V
R _O	Output Resistance	f = 1 KHz		16		mΩ
I _{sc}	Short Circuit Current	V _I = 35 V T _J = 25°C		0.45		Α
I _{scp}	Short Circuit Peak Current	$T_J = 25^{\circ}C$		2.2		Α

^(*) Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

ELECTRICAL CHARACTERISTICS OF L7885C (refer to the test circuits, T_J = 0 to 125°C, V_I = 14.5V, I_O = 500 mA, C_I = 0.33 μ F, C_O = 0.1 μ F unless otherwise specified).

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Vo	Output Voltage	T _J = 25°C	8.2	8.5	8.8	V
Vo	Output Voltage	$I_O = 5 \text{ mA to 1 A}$ $P_O \le 15W$ $V_I = 11 \text{ to 26 V}$	8.1	8.5	8.9	V
ΔV _O (*)	Line Regulation	$V_{I} = 11 \text{ to } 27 \text{ V}$ $T_{J} = 25^{\circ}\text{C}$			160	mV
		V _I = 11.5 to 17.5 V T _J = 25°C			80	
ΔV _O (*)	Load Regulation	$I_{O} = 5 \text{ mA to } 1.5 \text{ A}$ $T_{J} = 25^{\circ}\text{C}$			160	mV
		$I_{O} = 250 \text{ to } 750 \text{ mA}$ $T_{J} = 25^{\circ}\text{C}$			80	
I _d	Quiescent Current	T _J = 25°C			8	mA
ΔI_d	Quiescent Current Change	I _O = 5 mA to 1 A			0.5	mA
		V _I = 11 to 27 V			1	
$\Delta V_{O}/\Delta T$	Output Voltage Drift	I _O = 5 mA		-0.8		mV/°C
eN	Output Noise Voltage	B =10Hz to 100KHz $T_J = 25$ °C		55		μV/V _O
SVR	Supply Voltage Rejection	V _I = 12 to 22 V f = 120Hz	56			dB
V _d	Dropout Voltage	I _O = 1 A T _J = 25°C		2		V
R _O	Output Resistance	f = 1 KHz		16		mΩ
I _{sc}	Short Circuit Current	V _I = 35 V T _J = 25°C		0.45		Α
I _{scp}	Short Circuit Peak Current	T _J = 25°C		2.2		Α

^(*) Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

ELECTRICAL CHARACTERISTICS OF L7809C (refer to the test circuits, T_J = 0 to 125°C, V_I = 15V, I_O = 500 mA, C_I = 0.33 μ F, C_O = 0.1 μ F unless otherwise specified).

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Vo	Output Voltage	$T_J = 25^{\circ}C$	8.65	9	9.35	V
Vo	Output Voltage	$I_O = 5 \text{ mA to } 1 \text{ A}$ $P_O \le 15W$ $V_I = 11.5 \text{ to } 26 \text{ V}$	8.55	9	9.45	V
ΔV _O (*)	Line Regulation	$V_I = 11.5 \text{ to } 26 \text{ V}$ $T_J = 25^{\circ}\text{C}$			180	mV
		$V_{I} = 12 \text{ to } 18 \text{ V}$ $T_{J} = 25^{\circ}\text{C}$			90	
ΔV _O (*)	Load Regulation	$I_O = 5 \text{ mA to } 1.5 \text{ A}$ $T_J = 25^{\circ}\text{C}$			180	mV
		$I_{O} = 250 \text{ to } 750 \text{ mA}$ $T_{J} = 25^{\circ}\text{C}$			90	
I _d	Quiescent Current	$T_J = 25$ °C			8	mA
ΔI_{d}	Quiescent Current Change	I _O = 5 mA to 1 A			0.5	mA
		V _I = 11.5 to 26 V			1	
$\Delta V_O/\Delta T$	Output Voltage Drift	I _O = 5 mA		-1		mV/°C
eN	Output Noise Voltage	B =10Hz to 100KHz $T_J = 25$ °C		70		μV/V _O
SVR	Supply Voltage Rejection	V _I = 12 to 23 V f = 120Hz	55			dB
V _d	Dropout Voltage	$I_O = 1 \text{ A}$ $T_J = 25^{\circ}\text{C}$		2		V
R _O	Output Resistance	f = 1 KHz		17		mΩ
I _{sc}	Short Circuit Current	V _I = 35 V T _J = 25°C		0.40		Α
I _{scp}	Short Circuit Peak Current	$T_J = 25^{\circ}C$		2.2		Α

^(*) Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

ELECTRICAL CHARACTERISTICS OF L7812C (refer to the test circuits, T_J = 0 to 125°C, V_I = 19V, I_O = 500 mA, C_I = 0.33 μ F, C_O = 0.1 μ F unless otherwise specified).

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Vo	Output Voltage	T _J = 25°C	11.5	12	12.5	V
Vo	Output Voltage	$I_O = 5 \text{ mA to 1 A}$ $P_O \le 15W$ $V_I = 14.5 \text{ to 27 V}$	11.4	12	12.6	V
ΔV _O (*)	Line Regulation	V _I = 14.5 to 30 V T _J = 25°C			240	mV
		V _I = 16 to 22 V			120	
ΔV _O (*)	Load Regulation	$I_O = 5 \text{ mA to } 1.5 \text{ A}$ $T_J = 25^{\circ}\text{C}$			240	mV
		$I_{O} = 250 \text{ to } 750 \text{ mA}$ $T_{J} = 25^{\circ}\text{C}$			120	
I _d	Quiescent Current	T _J = 25°C			8	mA
Δl_d	Quiescent Current Change	I _O = 5 mA to 1 A			0.5	mA
		V _I = 14.5 to 30 V			1	
$\Delta V_{O}/\Delta T$	Output Voltage Drift	$I_O = 5 \text{ mA}$		-1		mV/°C
eN	Output Noise Voltage	B =10Hz to 100KHz $T_J = 25$ °C		75		μV/V _O
SVR	Supply Voltage Rejection	V _I = 15 to 25 V f = 120Hz	55			dB
V _d	Dropout Voltage	I _O = 1 A T _J = 25°C		2		V
R _O	Output Resistance	f = 1 KHz		18		mΩ
I _{sc}	Short Circuit Current	V _I = 35 V T _J = 25°C		0.35		Α
I _{scp}	Short Circuit Peak Current	$T_J = 25$ °C		2.2		Α

^(*) Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

ELECTRICAL CHARACTERISTICS OF L7815C (refer to the test circuits, T_J = 0 to 125°C, V_I = 23V, I_O = 500 mA, C_I = 0.33 μ F, C_O = 0.1 μ F unless otherwise specified).

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Vo	Output Voltage	T _J = 25°C	14.5	15	15.6	V
Vo	Output Voltage	$I_O = 5 \text{ mA to 1 A} \qquad P_O \le 15W$ $V_I = 17.5 \text{ to 30 V}$	14.25	15	15.75	V
ΔV _O (*)	Line Regulation	$V_{I} = 17.5 \text{ to } 30 \text{ V}$ $T_{J} = 25^{\circ}\text{C}$			300	mV
		$V_{I} = 20 \text{ to } 26 \text{ V}$ $T_{J} = 25^{\circ}\text{C}$			150	
ΔV _O (*)	Load Regulation	$I_O = 5 \text{ mA to } 1.5 \text{ A}$ $T_J = 25^{\circ}\text{C}$			300	mV
		$I_{O} = 250 \text{ to } 750 \text{ mA}$ $T_{J} = 25^{\circ}\text{C}$			150	
I _d	Quiescent Current	$T_J = 25^{\circ}C$			8	mA
ΔI_{d}	Quiescent Current Change	I _O = 5 mA to 1 A			0.5	mA
		V _I = 17.5 to 30 V			1	
$\Delta V_{O}/\Delta T$	Output Voltage Drift	I _O = 5 mA		-1		mV/°C
eN	Output Noise Voltage	B =10Hz to 100KHz $T_J = 25$ °C		90		μV/V _O
SVR	Supply Voltage Rejection	V _I = 18.5 to 28.5 V f = 120Hz	54			dB
V _d	Dropout Voltage	I _O = 1 A T _J = 25°C		2		V
R _O	Output Resistance	f = 1 KHz		19		mΩ
I _{sc}	Short Circuit Current	V _I = 35 V T _J = 25°C		0.23		Α
I _{scp}	Short Circuit Peak Current	$T_J = 25^{\circ}C$		2.2		Α

^(*) Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

ELECTRICAL CHARACTERISTICS OF L7818C (refer to the test circuits, T_J = 0 to 125°C, V_I = 26V, I_O = 500 mA, C_I = 0.33 μ F, C_O = 0.1 μ F unless otherwise specified).

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Vo	Output Voltage	T _J = 25°C	17.3	18	18.7	V
Vo	Output Voltage	$I_O = 5 \text{ mA to 1 A}$ $P_O \le 15W$ $V_I = 21 \text{ to 33 V}$	17.1	18	18.9	V
ΔV _O (*)	Line Regulation	$V_{I} = 21 \text{ to } 33 \text{ V}$ $T_{J} = 25^{\circ}\text{C}$			360	mV
		V _I = 24 to 30 V			180	
ΔV _O (*)	Load Regulation	$I_O = 5 \text{ mA to } 1.5 \text{ A}$ $T_J = 25^{\circ}\text{C}$			360	mV
		$I_{O} = 250 \text{ to } 750 \text{ mA}$ $T_{J} = 25^{\circ}\text{C}$			180	
I _d	Quiescent Current	T _J = 25°C			8	mA
Δl_d	Quiescent Current Change	I _O = 5 mA to 1 A			0.5	mA
		V _I = 21 to 33 V			1	
$\Delta V_{O}/\Delta T$	Output Voltage Drift	I _O = 5 mA		-1		mV/°C
eN	Output Noise Voltage	B =10Hz to 100KHz $T_J = 25$ °C		110		μV/V _O
SVR	Supply Voltage Rejection	V _I = 22 to 32 V f = 120Hz	53			dB
V _d	Dropout Voltage	I _O = 1 A T _J = 25°C		2		V
R _O	Output Resistance	f = 1 KHz		22		mΩ
I _{sc}	Short Circuit Current	V _I = 35 V T _J = 25°C		0.20		Α
I _{scp}	Short Circuit Peak Current	$T_J = 25$ °C		2.1		Α

^(*) Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

ELECTRICAL CHARACTERISTICS OF L7820C (refer to the test circuits, T_J = 0 to 125°C, V_I = 28V, I_O = 500 mA, C_I = 0.33 μ F, C_O = 0.1 μ F unless otherwise specified).

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Vo	Output Voltage	T _J = 25°C	19.2	20	20.8	V
Vo	Output Voltage	$I_O = 5$ mA to 1 A $P_O \le 15$ W $V_I = 23$ to 35 V	19	20	21	V
ΔV _O (*)	Line Regulation	$V_I = 22.5 \text{ to } 35 \text{ V}$ $T_J = 25^{\circ}\text{C}$			400	mV
		$V_{I} = 26 \text{ to } 32 \text{ V}$ $T_{J} = 25^{\circ}\text{C}$			200	
ΔV _O (*)	Load Regulation	$I_O = 5 \text{ mA to } 1.5 \text{ A}$ $T_J = 25^{\circ}\text{C}$			400	mV
		$I_{O} = 250 \text{ to } 750 \text{ mA}$ $T_{J} = 25^{\circ}\text{C}$			200	
I _d	Quiescent Current	T _J = 25°C			8	mA
ΔI_{d}	Quiescent Current Change	$I_O = 5 \text{ mA to 1 A}$			0.5	mA
		V _I = 23 to 35 V			1	
$\Delta V_{O}/\Delta T$	Output Voltage Drift	I _O = 5 mA		-1		mV/°C
eN	Output Noise Voltage	B =10Hz to 100KHz $T_J = 25$ °C		150		μV/V _O
SVR	Supply Voltage Rejection	V _I = 24 to 35 V f = 120Hz	52			dB
V _d	Dropout Voltage	I _O = 1 A T _J = 25°C		2		V
R _O	Output Resistance	f = 1 KHz		24		mΩ
I _{sc}	Short Circuit Current	V _I = 35 V T _J = 25°C		0.18		Α
I _{scp}	Short Circuit Peak Current	T _J = 25°C		2.1		Α

^(*) Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

ELECTRICAL CHARACTERISTICS OF L7824C (refer to the test circuits, T_J = 0 to 125°C, V_I = 33V, I_O = 500 mA, C_I = 0.33 μ F, C_O = 0.1 μ F unless otherwise specified).

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Vo	Output Voltage	T _J = 25°C	23	24	25	V
Vo	Output Voltage	$I_O = 5 \text{ mA to 1 A}$ $P_O \le 15W$ $V_I = 27 \text{ to 38 V}$	22.8	24	25.2	V
ΔV _O (*)	Line Regulation	$V_{I} = 27 \text{ to } 38 \text{ V}$ $T_{J} = 25^{\circ}\text{C}$			480	mV
		V _I = 30 to 36 V			240	
ΔV _O (*)	Load Regulation	$I_O = 5 \text{ mA to } 1.5 \text{ A}$ $T_J = 25^{\circ}\text{C}$			480	mV
		$I_{O} = 250 \text{ to } 750 \text{ mA}$ $T_{J} = 25^{\circ}\text{C}$			240	
I _d	Quiescent Current	T _J = 25°C			8	mA
Δl_d	Quiescent Current Change	I _O = 5 mA to 1 A			0.5	mA
		V _I = 27 to 38 V			1	
$\Delta V_{O}/\Delta T$	Output Voltage Drift	$I_O = 5 \text{ mA}$		-1.5		mV/°C
eN	Output Noise Voltage	B =10Hz to 100KHz $T_J = 25$ °C		170		μV/V _O
SVR	Supply Voltage Rejection	V _I = 28 to 38 V f = 120Hz	50			dB
V _d	Dropout Voltage	I _O = 1 A T _J = 25°C		2		V
R _O	Output Resistance	f = 1 KHz		28		mΩ
I _{sc}	Short Circuit Current	V _I = 35 V T _J = 25°C		0.15		Α
I _{scp}	Short Circuit Peak Current	T _J = 25°C		2.1		Α

^(*) Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

Figure 4 : Dropout Voltage vs Junction Temperature

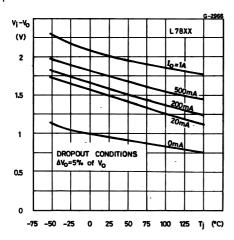


Figure 5 : Peak Output Current vs Input/output Differential Voltage

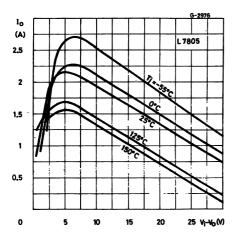


Figure 6 : Supply Voltage Rejection vs Frequency

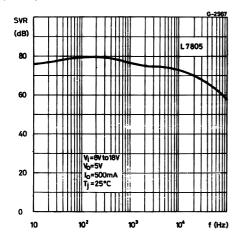


Figure 7 : Output Voltage vs Junction Temperature

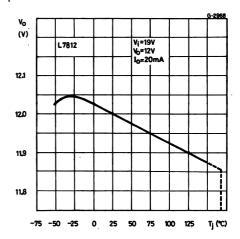


Figure 8 : Output Impedance vs Frequency

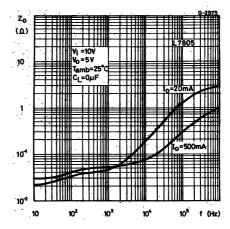


Figure 9 : Quiescent Current vs Junction Temperature

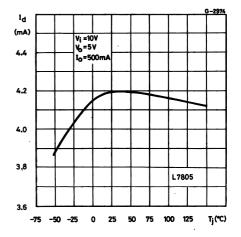


Figure 10: Load Transient Response

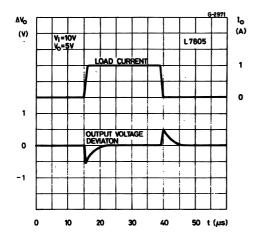


Figure 12: Quiescent Current vs Input Voltage

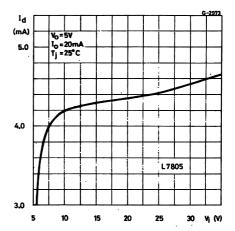


Figure 11: Line Transient Response

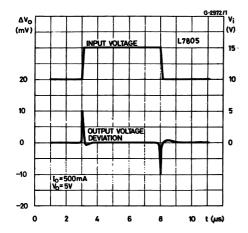
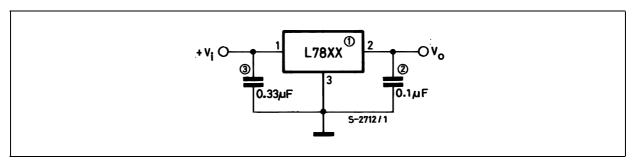


Figure 13: Fixed Output Regulator



- NOTE:
 1. To specify an output voltage, substitute voltage value for "XX".
 2. Although no output capacitor is need for stability, it does improve transient response.
 3. Required if regulator is locate an appreciable distance from power supply filter.

Figure 14: Current Regulator

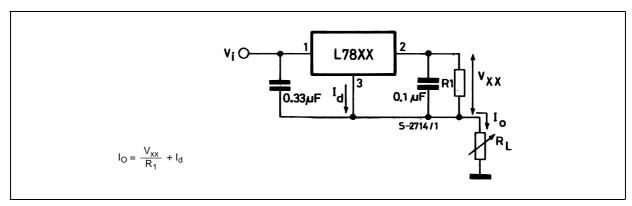


Figure 15 : Circuit for Increasing Output Voltage

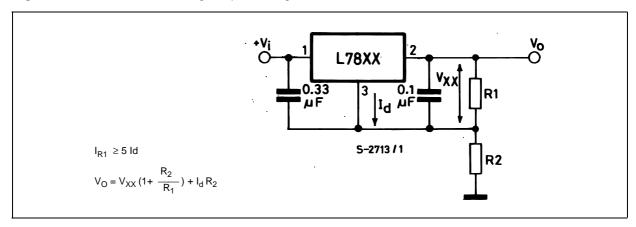


Figure 16: Adjustable Output Regulator (7 to 30V)

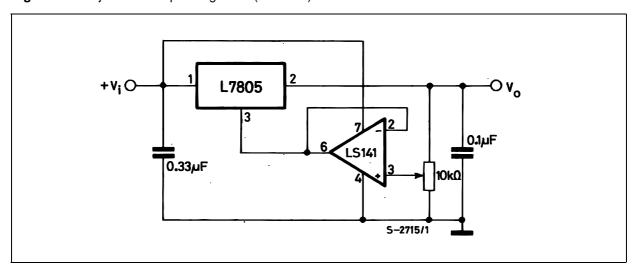


Figure 17: 0.5 to 10V Regulator

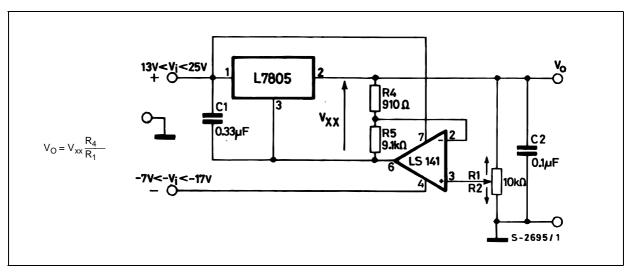


Figure 18: High Current Voltage Regulator

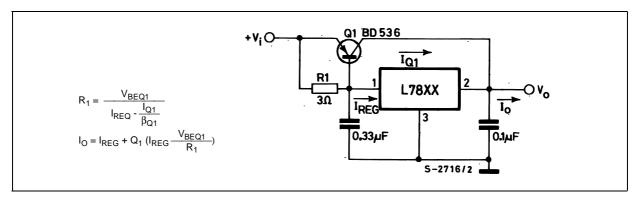


Figure 19: High Output Current with Short Circuit Protection

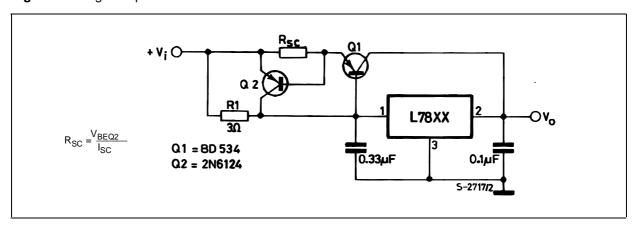


Figure 20 : Tracking Voltage Regulator

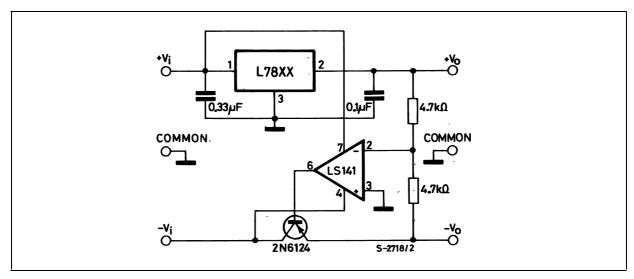
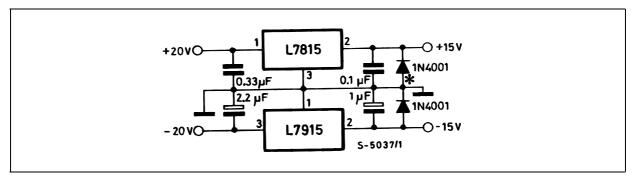


Figure 21 : Split Power Supply (± 15V - 1 A)



^{*} Against potential latch-up problems.

Figure 22 : Negative Output Voltage Circuit

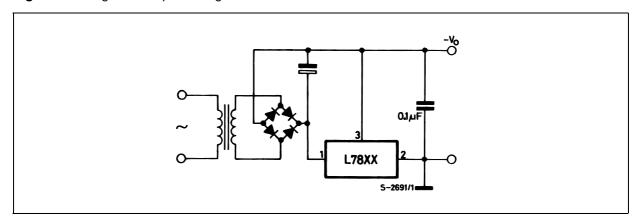


Figure 23 : Switching Regulator

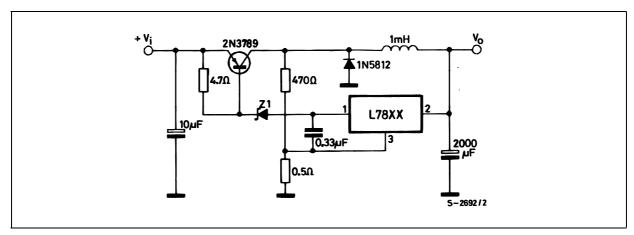


Figure 24 : High Input Voltage Circuit

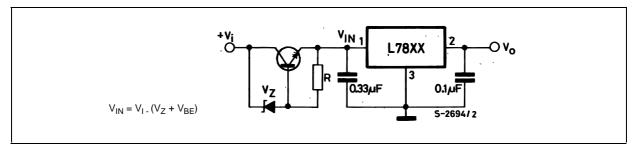


Figure 25 : High Input Voltage Circuit

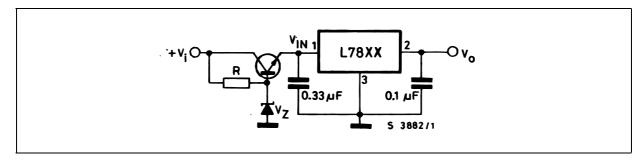


Figure 26 : High Output Voltage Regulator

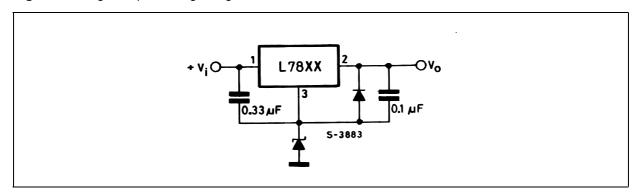


Figure 27: High Input and Output Voltage

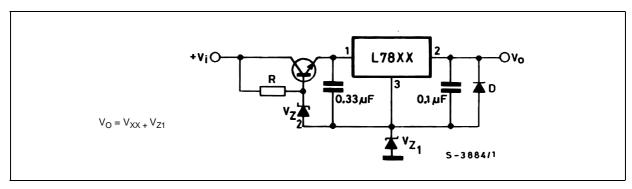


Figure 28: Reducing Power Dissipation with Dropping Resistor

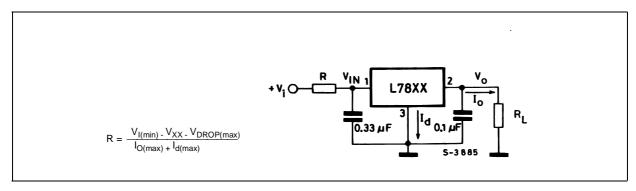


Figure 29: Remote Shutdown

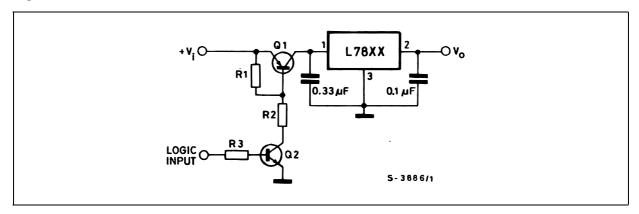
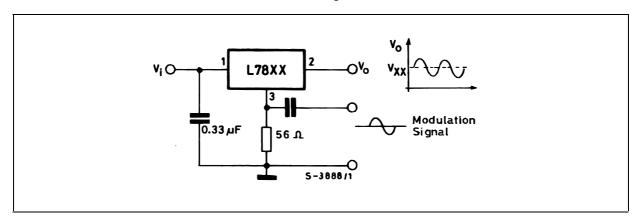
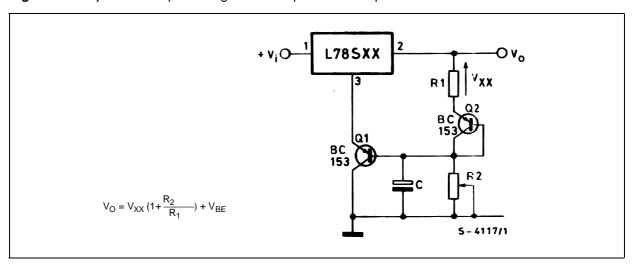


Figure 30 : Power AM Modulator (unity voltage gain, $I_{O} \le 0.5$)



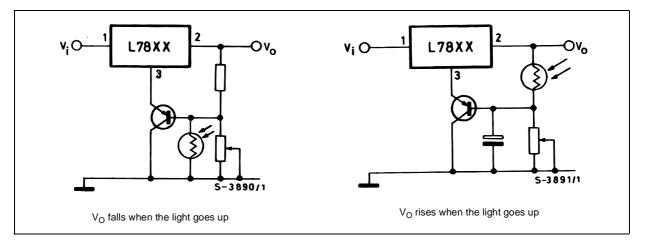
NOTE: The circuit performs well up to 100 KHz.

Figure 31 : Adjustable Output Voltage with Temperature Compensation



NOTE: Q_2 is connected as a diode in order to compensate the variation of the Q_1 V_{BE} with the temperature. C allows a slow rise time of the V_O .

Figure 32 : Light Controllers ($V_{Omin} = V_{XX} + V_{BE}$)



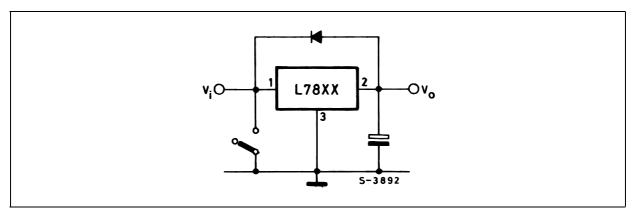
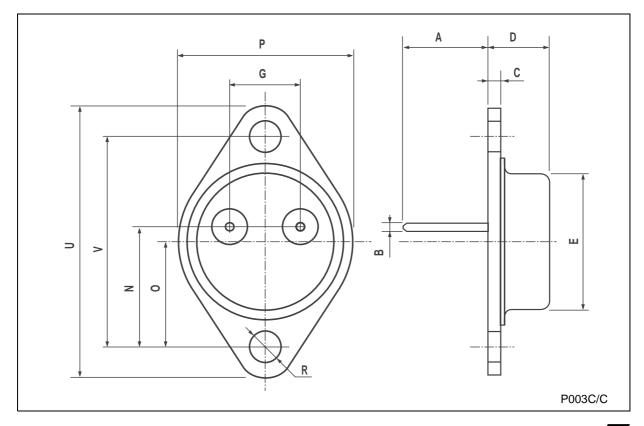


Figure 33 : Protection against Input Short-Circuit with High Capacitance Loads

Application with high capacitance loads and an output voltage greater than 6 volts need an external diode (see fig. 33) to protect the device against input short circuit. In this case the input voltage falls rapidly while the output voltage decrease slowly. The capacitance discharges by means of the Base-Emitter junction of the series pass transistor in the regulator. If the energy is sufficiently high, the transistor may be destroyed. The external diode by-passes the current from the IC to ground.

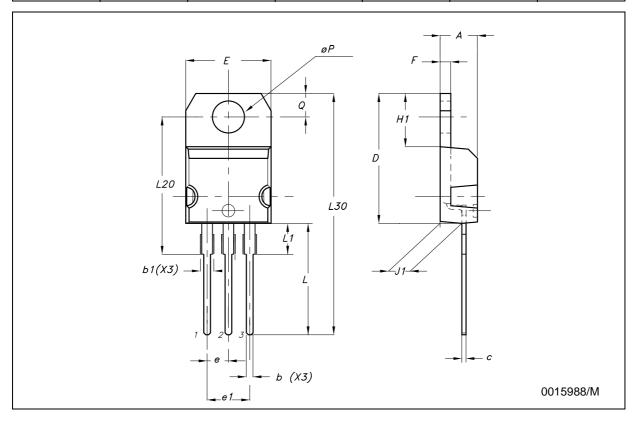
TO-3 MECHANICAL DATA

DIM		mm.			inch	
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
А		11.85			0.466	
В	0.96	1.05	1.10	0.037	0.041	0.043
С			1.70			0.066
D			8.7			0.342
E			20.0			0.787
G		10.9			0.429	
N		16.9			0.665	
Р			26.2			1.031
R	3.88		4.09	0.152		0.161
U			39.5			1.555
V		30.10			1.185	



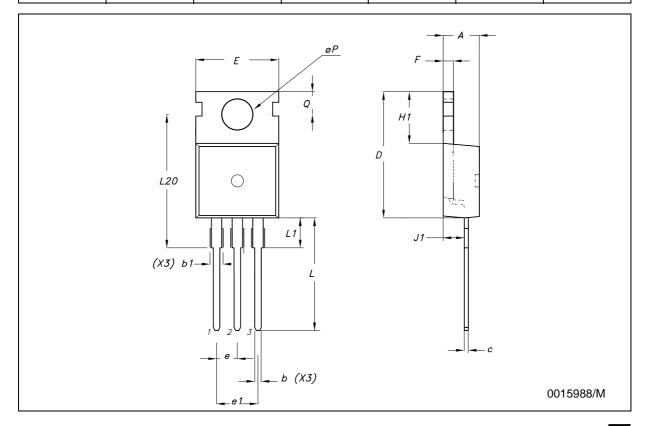
TO-220 (A TYPE) MECHANICAL DATA

DIM.		mm.		inch		
DIIVI.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
Α	4.40		4.60	0.173		0.181
b	0.61		0.88	0.024		0.034
b1	1.15		1.70	0.045		0.067
С	0.49		0.70	0.019		0.027
D	15.25		15.75	0.600		0.620
Е	10.0		10.40	0.393		0.409
е	2.4		2.7	0.094		0.106
e1	4.95		5.15	0.194		0.203
F	1.23		1.32	0.048		0.051
H1	6.2		6.6	0.244		0.260
J1	2.40		2.72	0.094		0.107
L	13.0		14.0	0.511		0.551
L1	3.5		3.93	0.137		0.154
L20		16.4			0.645	
L30		28.9			1.138	
φР	3.75		3.85	0.147		0.151
Q	2.65		2.95	0.104		0.116



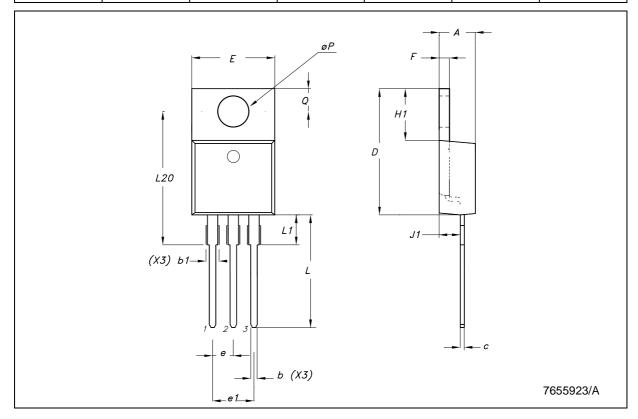
TO-220 (C TYPE) MECHANICAL DATA

DIM.		mm.			inch			
DIIVI.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.		
Α	4.30		4.70	0.169		0.185		
b	0.70		0.90	0.028		0.035		
b1	1.42		1.62	0.056		0.064		
С	0.45		0.60	0.018		0.024		
D		15.70			0.618			
Е	9.80		10.20	0.386		0.402		
е		2.54			0.100			
e1		5.08			0.200			
F	1.25		1.39	0.049		0.055		
H1		6.5			0.256			
J1	2.20		2.60	0.087		0.202		
L	12.88		13.28	0.507		0.523		
L1		3			0.118			
L20	15.70		16.1	0.618		0.634		
L30		28.9			1.138			
φР	3.50		3.70	0.138		0.146		
Q	2.70		2.90	0.106		0.114		



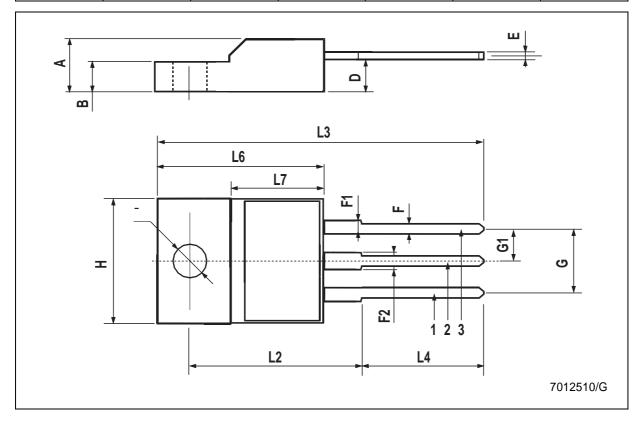
TO-220 (E TYPE) MECHANICAL DATA

DIM		mm.			inch		
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.	
А	4.47		4.67	0.176		0.184	
b	0.70		0.91	0.028		0.036	
b1	1.17		1.37	0.046		0.054	
С	0.31		0.53	0.012		0.021	
D	14.60		15.70	0.575		0.618	
E	9.96		10.36	0.392		0.408	
е		2.54			0.100		
e1		5.08			0.200		
F	1.17		1.37	0.046		0.054	
H1	6.1		6.8	0.240		0.268	
J1	2.52		2.82	0.099		0.111	
L	12.70		13.80	0.500		0.543	
L1	3.20		3.96	0.126		0.156	
L20	15.21		16.77	0.599		0.660	
φР	3.73		3.94	0.147		0.155	
Q	2.59		2.89	0.102		0.114	



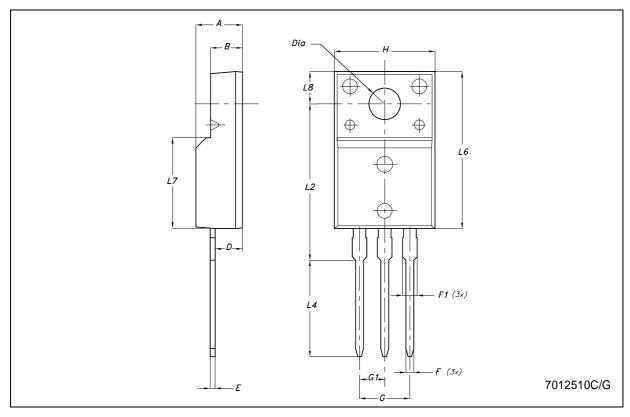
TO-220FP MECHANICAL DATA

DIM.		mm.	nm. inch		inch		
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.	
А	4.40		4.60	0.173		0.181	
В	2.5		2.7	0.098		0.106	
D	2.5		2.75	0.098		0.108	
Е	0.45		0.70	0.017		0.027	
F	0.75		1	0.030		0.039	
F1	1.15		1.50	0.045		0.059	
F2	1.15		1.50	0.045		0.059	
G	4.95		5.2	0.194		0.204	
G1	2.4		2.7	0.094		0.106	
Н	10.0		10.40	0.393		0.409	
L2		16			0.630		
L3	28.6		30.6	1.126		1.204	
L4	9.8		10.6	0.385		0.417	
L6	15.9		16.4	0.626		0.645	
L7	9		9.3	0.354		0.366	
DIA.	3		3.2	0.118		0.126	



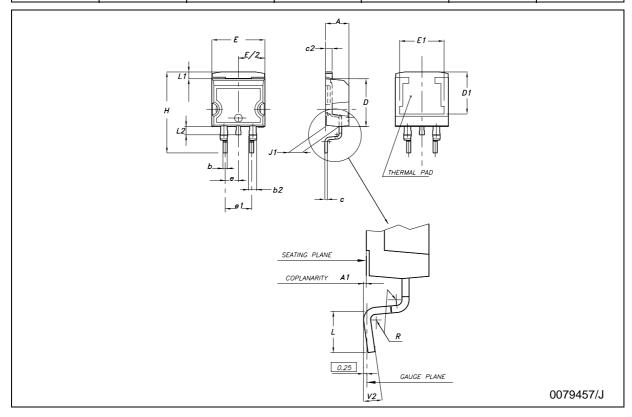
TO-220FM MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
А	4.50		4.90	0.177		0.193
В	3.04		3.44	0.120		0.135
D	2.56		2.96	0.101		0.117
Е	0.45	0.50	0.60	0.018	0.020	0.024
F	0.70		0.90	0.028		0.035
F1			1.47			0.058
G		5.08			0.200	
G1	2.34	2.54	2.74	0.092	0.100	0.108
Н	9.96		10.36	0.392		0.408
L2		15.8			0.622	
L4	9.45		10.05	0.372		0.396
L6	15.67		16.07	0.617		0.633
L7	8.99		9.39	0.354		0.370
L8		3.30			0.130	
DIA.	3.08		3.28	0.121		0.129



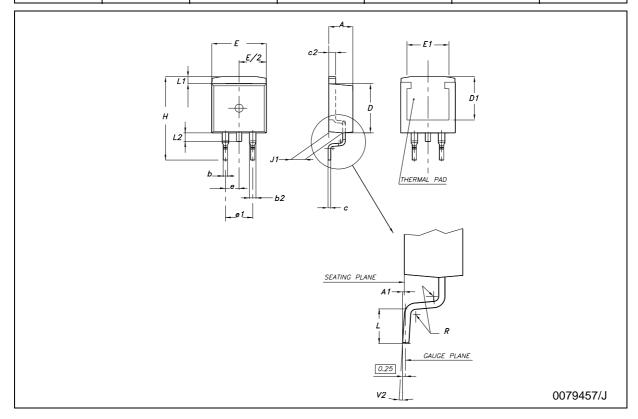
D²PAK (A TYPE) MECHANICAL DATA

DIM.		mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.	
Α	4.4		4.6	0.173		0.181	
A1	0.03		0.23	0.001		0.009	
b	0.7		0.93	0.027		0.036	
b2	1.14		1.7	0.044		0.067	
С	0.45		0.6	0.017		0.023	
c2	1.23		1.36	0.048		0.053	
D	8.95		9.35	0.352		0.368	
D1	8			0.315			
Е	10		10.4	0.393		0.409	
E1	8.5			0.335			
е		2.54			0.100		
e1	4.88		5.28	0.192		0.208	
Н	15		15.85	0.590		0.624	
J1	2.49		2.69	0.098		0.106	
L	2.29		2.79	0.090		0.110	
L1	1.27		1.4	0.050		0.055	
L2	1.3		1.75	0.051		0.069	
R		0.4			0.016		
V2	0°		8°	0°		8°	



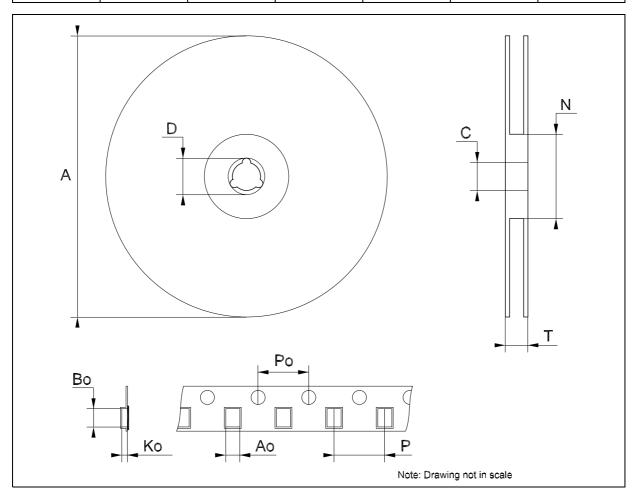
D²PAK (C TYPE) MECHANICAL DATA

DIM.		mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.	
Α	4.3		4.7	0.169		0.185	
A1	0		0.20	0.000		0.008	
b	0.70		0.90	0.028		0.035	
b2	1.17		1.37	0.046		0.054	
С	0.45	0.50	0.6	0.018	0.020	0.024	
c2	1.25	1.30	1.40	0.049	0.051	0.055	
D	9.0	9.2	9.4	0.354	0.362	0.370	
D1	7.5			0.295			
E	9.8		10.2	0.386		0.402	
E1	7.5			0.295			
е		2.54			0.100		
e1		5.08			0.200		
Н	15	15.30	15.60	0.591	0.602	0.614	
J1	2.20		2.60	0.087		0.102	
L	1.79		2.79	0.070		0.110	
L1	1.0		1.4	0.039		0.055	
L2	1.2		1.6	0.047		0.063	
R		0.3			0.012		
V2	0°		3°	0°		3°	



Tape & Reel D²PAK-P²PAK-D²PAK/A-P²PAK/A MECHANICAL DATA

DIM.		mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.	
Α			180			7.086	
С	12.8	13.0	13.2	0.504	0.512	0.519	
D	20.2			0.795			
N	60			2.362			
Т			14.4			0.567	
Ao	10.50	10.6	10.70	0.413	0.417	0.421	
Во	15.70	15.80	15.90	0.618	0.622	0.626	
Ko	4.80	4.90	5.00	0.189	0.193	0.197	
Ро	3.9	4.0	4.1	0.153	0.157	0.161	
Р	11.9	12.0	12.1	0.468	0.472	0.476	



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